



## CMOS 256 X 256 DIGITAL SWITCHING MATRIX

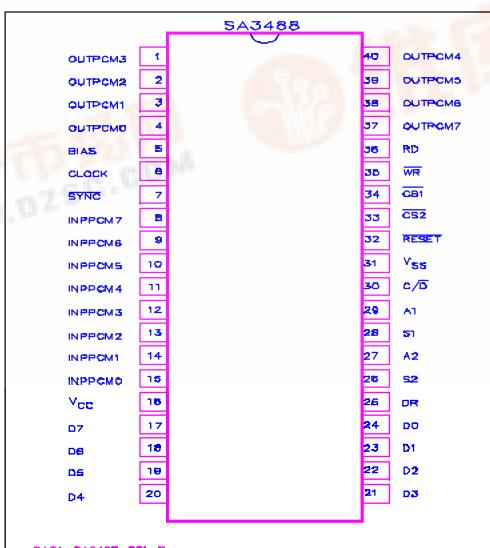
### FEATURES

- Hardware (pin-to-pin) and software compatible with M088 and M3488
- 256 input and 256 output channel digital switching matrix
- Building block designed for large capacity electronic exchanges, subsystems and PABX
- Non-blocking single stage and higher capacity blocks (512 or 1024 channels)
- European and U.S. standard compatible (32/24 serial channels per frame)
- PCM inputs and outputs mutually compatible
- Actual input-output channel connections stored and modified via an on chip 8-bit parallel microprocessor interface
- 6 main “Functions” or “Instructions” available
- Typical Bit Rate : 2Mbit/s
- Typical Synchronization Rate : 8KHz (time frame is 125µs)
- 5V power supply with internally generated bias voltage
- MOS & TTL input/output levels compatible

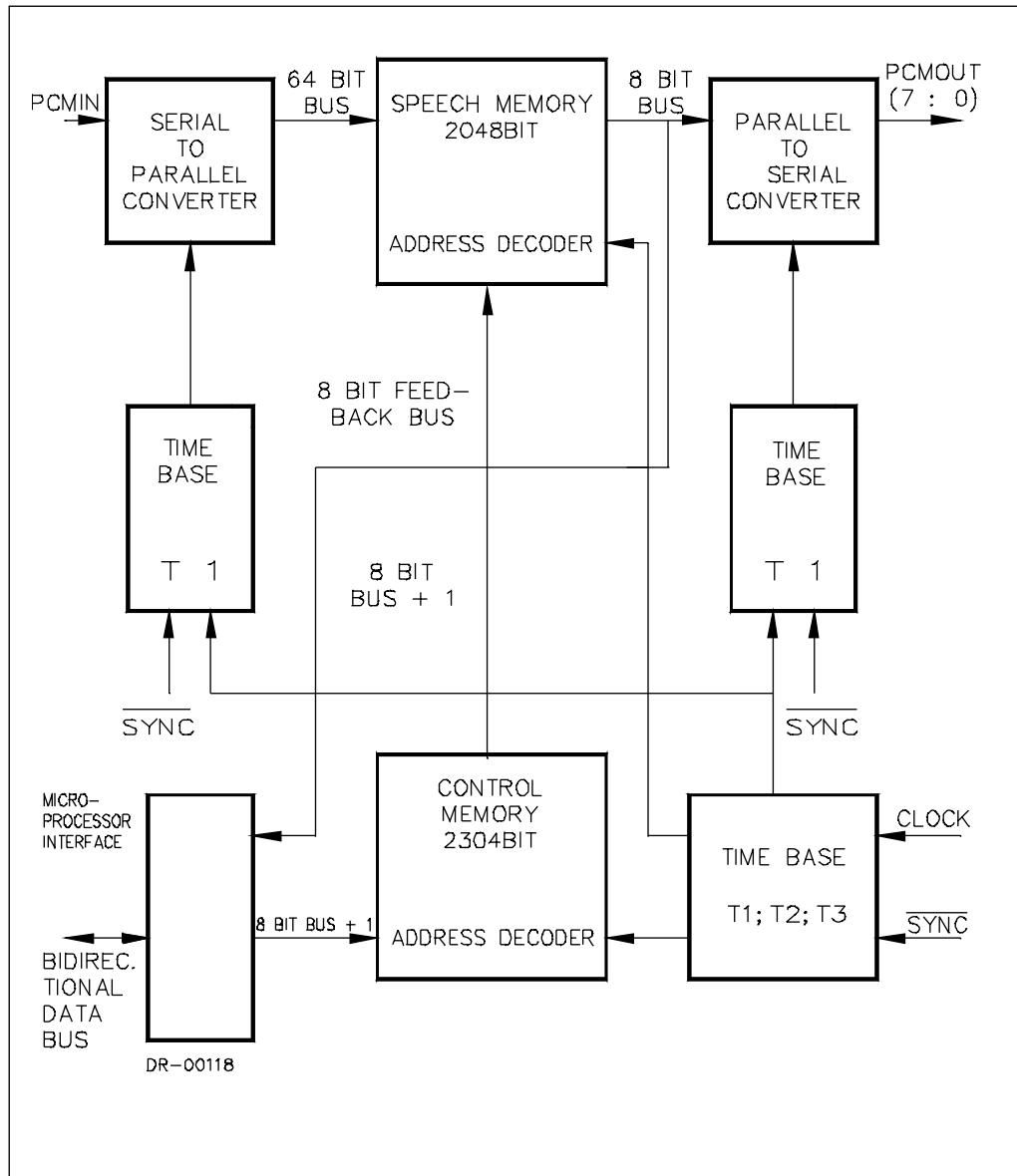
### DESCRIPTION

The SA3488 is a non-blocking digital switching matrix that is capable of routing 256 input channels to any of 256 output channels. Data is fed into and out of the device via eight serial PCM input and output channels at 2MBits/sec. The device can connect or disconnect each input channel with any output channel, as well as carry out other functions which are user programmable via an eight bit parallel microprocessor interface. The SA3488 sees its primary use as a building block in high volume electronic exchanges, voice data, PABX and other standard data communications applications. It can be easily configured for operation in PCM 24 or PCM 30 formats.

### PIN CONNECTIONS:



## BLOCK DIAGRAM



**ABSOLUTE MAXIMUM RATINGS \***

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.3 to 7	V
$V_I$	Input Voltage	-0.3 to 7	V
$V_O$	Off State Output	7	V
$P_{tot}$	Total Package Power Dissipation	1.5	W
$T_{stg}$	Storage Temperature Range	-40 to +125	°C
$T_{op}$	Operating Temperature Range	0 to +70	°C

\* Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other condition above those indicated in the operation sections of this specification, is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	4.75 to 5.25	V
$V_I$	Input Voltage	0 to 5.25	V
$V_O$	Off State Input Voltage	0 to 5.25	V
CLOCK Freq.	Input Clock Frequency	4.096	MHz
SYNC Freq.	Input Synchronization	8	KHz
$T_{op}$	Operating Temperature	0 to 70	°C

**CAPACITANCES (Measuring freq. = 1MHz;  $T_{op}$  = 0 to 70°C; unused pins tied to  $V_{SS}$ )**

Symbol	Parameter	Pins	Min.	Typ.	Max.	Unit
$C_I$	Input Capacitance	6 to 15; 26 to 30; 32 to 36			5	pf
$C_{I/O}$	I/O Capacitance	20 to 24			15	pf
$C_O$	Output Capacitance	1 to 4; 17 to 19; 37 to 40			10	pf

**D.C. ELECTRICAL CHARACTERISTICS ( $T_{amb} = 0$  to  $70^{\circ}\text{C}$ ,  $V_{CC} = 5\text{V} \pm 5\%$ )**All D.C. characteristics are valid  $250\mu\text{s}$  after  $V_{CC}$  and clock have been applied.

Symbol	Parameter	Pins	Test Condition	Min.	Typ.	Max.	Unit
$V_{ILC}$	Clock Input Low Level	6		-0.3		0.8	V
$V_{IHC}$	Clock Input High Level	6		2.4		$V_{CC}$	V
$V_{IL}$	Input Low Level	7 to 15 20 to 24 26 to 30 32 to 36		-0.3		0.8	V
$V_{IH}$	Input High Level	7 to 15 20 to 24 26 to 30 32 to 36		2.0		$V_{CC}$	V
$V_{OL}$	Output Low Level	17 to 25	$I_{OL} = 1.8\text{mA}$			0.4	V
$V_{OH}$	Output High Level	17 to 25	$I_{OH} = 250\mu\text{A}$	2.4			V
$V_{OL}$	PCM Output Low Level	1 to 4 37 to 40	$I_{OL} = 2.0\text{mA}$			0.4	V
$I_{IL}$	Input Leakage Current	6 to 15 26 to 30 32 to 36	$V_{IN} = 0$ to $V_{CC}$			10	$\mu\text{A}$
$I_{DL}$	Data Bus Leakage Current	17 to 24	$V_{IN} = 0$ to $V_{CC}$ $V_{CC}$ applied; Pins 35 and 36 tied to $V_{CC}$ , after Device Initialization			$\pm 10$	$\mu\text{A}$
$I_{CC}$	Supply Current	16	Clock Freq.= 4.096MHz			180	mA

**A.C. ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 0$  to  $70^{\circ}C$ ,  $V_{CC} = 5V \pm 5\%$ )

All A.C. characteristics are valid 250 $\mu$ s after  $V_{CC}$  and clock have been applied.  $C_L$  is the max. capacitive load and  $R_L$  the test pull up resistor.

Signal	Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
CK (clock)	$t_{CK}$	Clock Period		230	25	25	ns
	$t_{WL}$	Clock Low Level Width		100			ns
	$t_{WH}$	Clock High Level Width		100			ns
	$t_R$	Rise Time					ns
	$t_F$	Fall Time					ns
SYNC	$t_{SL}$	Low Level Setup Time		80	$t_{CK}$		ns
	$t_{HL}$	Low Level Hold Time		40			ns
	$t_{SH}$	High Level Setup Time		80			ns
	$t_{WH}$	High Level Width					ns
PCM input Busses	$t_S$	Setup Time		-5			ns
	$t_H$	Hold Time		45			ns
PCM Output Busses	$t_{PDmin}$	Propagation time referred to CK low level	$CL = 50\text{pf}, R_L = 2\text{K}$	45		200	ns
	$t_{PDmax}$	Propagation time referred to CK high level					ns
RESET	$t_{SL}$	Low Level Setup Time		100	$t_{CK}$		ns
	$t_{HL}$	Low Level Hold Time		50			ns
	$t_{SH}$	High Level Setup Time		90			ns
	$t_{WH}$	High Level Width					ns
WR	$t_{WL}$	Low Level Width	$t_{REP} = 40 + 2 t_{CK} + t_{WL(CK)} + t_{R(CK)}$	150	$t_{CK}$ see formula	0	ns
	$t_{WH}$	High Level Width					ns
	$t_{REP}$	Repetition Interval between Active Pulses					ns
	$t_{SH}$	High Level Setup Time to Active Read Strobe		20			ns
	$t_{HH}$	High Level Hold Time from Active Read Strobe					ns
	$t_R$	Rise Time				60	ns
	$t_F$	Fall Time					ns
RD	$t_{WL}$	Low Level Width	$t_{REP} = 40 + 2 t_{CK} + t_{WL} + t_R$	180	$t_{CK}$ see formula	0	ns
	$t_{WH}$	High Level Width					ns
	$t_{REP}$	Repetition Interval between Active Pulses					ns
	$t_{SH}$	High Level Setup Time to Active Read Strobe		20			ns
	$t_{HH}$	High Level Hold Time from Active Write Strobe					ns
	$t_R$	Rise Time				60	ns
	$t_F$	Fall Time					ns

## A.C. ELECTRICAL CHARACTERISTICS (Cont.)

Signal	Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
CS1, CS2	$t_{SL(\overline{CS}-\overline{WR})}$	Low level setup time to $\overline{WR}$ falling edge	Active Case	0			ns
	$t_{HL(\overline{CS}-\overline{WR})}$	Low level hold time from $\overline{WR}$ rising edge	Active Case	0			ns
	$t_{SH(\overline{CS}-\overline{WR})}$	High level setup time to $\overline{WR}$ falling edge	Inactive Case	0			ns
	$t_{HH(\overline{CS}-\overline{WR})}$	High level hold time from $\overline{WR}$ rising edge	Inactive Case	0			ns
	$t_{SL(\overline{CS}-\overline{RD})}$	Low level setup time to $\overline{RD}$ falling edge	Active Case	0			ns
	$t_{HL(\overline{CS}-\overline{RD})}$	Low level hold time from $\overline{RD}$ rising edge	Active Case	0			ns
	$t_{SH(\overline{CS}-\overline{RD})}$	High level setup time to $\overline{RD}$ falling edge	Inactive Case	0			ns
	$t_{HH(\overline{CS}-\overline{RD})}$	High level hold time from $\overline{RD}$ rising edge	Inactive Case	0			ns
C/D	$t_{S(\overline{C/D}-\overline{WR})}$	Setup time to write strobe end			130		ns
	$t_{H(\overline{C/D}-\overline{WR})}$	Hold time from write strobe end			25		ns
	$t_{S(\overline{C/D}-\overline{WR})}$	Setup time to read strobe start			20		ns
	$t_{H(\overline{C/D}-\overline{WR})}$	Hold time from read strobe end			25		ns
A1,S1, A2,S2 (match inputs)	$t_{S(match-\overline{WR})}$	Setup time to write strobe end			130		ns
	$t_{H(match-\overline{WR})}$	Hold time from strobe end			25		ns
	$t_{S(match-\overline{RD})}$	Setup time to read strobe start			20		ns
	$t_{H(match-\overline{RD})}$	Hold time from read strobe end			25		ns
DR (data ready)	$t_w$ $t_{PD}$	Low state width DR output delay from write strobe end (active command)	Instructions 5,6			$2 t_{CK}$	ns
			Instructions 5, $C_L = 50\text{pf}$			$14 t_{CK}$	ns

## A.C. ELECTRICAL CHARACTERISTICS (Cont.)

Signal	Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
D0 to D7 (Interface bus)	$t_{S(\overline{BUS-WR})}$ $t_{H(\overline{BUS-WR})}$ $t_{PD(BUS)}$ $t_{HZ(BUS)}$	Input setup time to write strobe end Input hold time from write strobe end Propagation time from (active) falling edge of read strobe Propagation time from (active) rising edge of read strobe to high impedance state	$C_L = 200\text{pf}$	130 25		120 80	ns ns ns ns

## PIN DESCRIPTION

Pin	Designation	Description
17	D7	
18	D6	
19	D5	
20	D4	
21	D3	
22	D2	
23	D1	
24	D0	
30	C/D	In a write operation $C/\bar{D} = 0$ qualifies bus content as data, while $C/\bar{D} = 1$ qualifies it as a opcode. In a read operation $C/\bar{D} = 0$ selects OR1 whereas $C/\bar{D} = 1$ selects OR2.
33	$\overline{CS2}$	Chip select pins. Enable the device to perform valid read and write operations (active low). The two pins allow for row column selection for different types of microprocessors; normally though one is tied low.
34	$\overline{CS1}$	
26	S2	
27	A2	
29	A1	Address select or match pins. With S1 and S2 hardwired to ground or $V_{CC}$ signals on A1 and A2 give rise to a 28S1 matched or unmatched condition i.e. $S1=A1$ , $S2=A2 \Rightarrow$ a matched condition. Since in a matrix structure, devices in the same row share the same PCM output bus, instructions pertaining to channel connections (matched condition), must be processed as channel disconnections in the other devices (unmatched condition). Two channels can therefore never collide.
35	$\overline{WR}$	When $\overline{CS1}$ and $\overline{CS2}$ are low, $\overline{WR}$ enables data transfer from the microprocessor to the device. Data, opcode and control signals are latched on the rising edge of $\overline{WR}$ . To ensure simultaneous instruction execution in a multichip configuration the $\overline{WR}$ rising edge must be 20 to $20 + t_{WL(CK)}$ nsec late relative to the clock falling edge.
36	$\overline{RD}$	When $\overline{CS1}$ and $\overline{CS2}$ are low and a matched condition exists, a low level on $\overline{RD}$ enables OR1 or OR2 for a read operation. In addition the rising edge of $\overline{RD}$ latches $\overline{C/D}$ and the matched condition pins in order to direct the internal flow of operations. In a multichip configuration the same timing requirement must be met as in the $\overline{WR}$ case.

## Pin Description (Cont.)

Pin	Designation	Description
32	RESET	This pin is used to initialise the device. The <u>initialisation</u> routine takes one time frame whatever the RESET pulse width (one clock cycle minimum). All internal registers are set 'high' and the control memory is set to all 'ones' i.e. channel disconnection. The data bus is pulled to a high impedance state as well as the PCM output channels.
25	DR	DR is the data ready pin which is normally high. If DR goes low the following information is available via this pin. <ol style="list-style-type: none"> <li>1. Invalid instruction code (The pin is held low until a valid instruction is loaded).</li> <li>2. An active output channel was found in a matrix of devices with the same CS pins during the execution of instruction 5. DR is low for two clock cycles.</li> <li>3. Status register 2 was loaded with the total number of messages in time slot 0 during the execution of instruction 5. DR is active low for two clock cycles.</li> </ol>
6	CLOCK	Input clock frequency is typically 4.096Mhz. This signal will set the internal input/ output channel bit rate to 2.048 Mbits/sec. The bit rate is set by division of the master clock frequency.
7	SYNC	The input synchronisation signal frequency is 8kHz and is active low. Internally generated time bases that <u>maintain</u> sequential addressing are synchronised via the SYNC signal.
8	INP PCM7	The input PCM bus accepts a standard data rate of 2MBits/sec.
9	INP PCM6	
10	INP PCM5	
11	INP PCM4	
12	INP PCM3	
13	INP PCM2	
14	INP PCM1	
15	INP PCM0	

**Pin Description (Cont.)**

<b>Pin</b>	<b>Designation</b>	<b>Description</b>
37 output OR connection. multichip are driven in delay time up to:	OUT PCM7 38	Output PCM channel bit rate is also 2MBits/sec. The OUT PCM6 buffers are open drain simulating a wired 39 OUT PCM5 This minimises current spike problems in 40 OUT PCM4 configurations. Input and output channels 1 OUT PCM3 such a manner as to reduce any analogue
2 3	OUT PCM2 OUT PCM1	Time delay max = 1 bit time-(clock high prop. time - Clock low prop. time).
4 5	OUT PCM0 BIAS	Internally generated bias voltage (-2.5 to -3.0V for $V_{cc}$ in the operating range). A maximum of 220pf capacitor connected to pin 5 provides improved filtering.

## FUNCTIONAL OVERVIEW

The SA3488 is intended for large telephone switching systems, mainly central exchanges, digital line concentrators and private branch exchanges where a distributed microcomputer control approach is extensively used. It consists of a speech memory (SM), a control memory (CM), a serial/parallel and a parallel/serial converter, an internal parallel bus, an interface (8 data lines, 11 control signals) and dedicated logic. By means of repeated clock division two time bases are generated. These are preset from an external synchronization signal to two specific count numbers so that sequential scanning of the bases give synchronous addresses to the memories and I/O channel controls. Different preset count numbers are needed because of processing delays and data path direction. The time-base for output channels is advanced with respect to the actual time. Each serial PCM input channel is converted to parallel data and stored in the speech memory at the beginning of any new time slot (according to first timebase) in the location determined by input pin number and time slot number. The control memory CM maintains the correspondences between input and output channels. More exactly, for any output pin/output channel combination the control memory gives either the full address of the speech memory location involved in the PCM transfer or an 8-bit word to be supplied to the parallel/serial output converter. A 9<sup>th</sup> bit at each CM location defines the data source for output links; low for SM, high for CM.

The late timebase is used to scan the output channels and to determine the pins to be serviced within each channel. Enough idle cycles are left to the microprocessor for synchronous instruction processing. Two 8-bit registers OR1 and OR2 supply feedback data for control or diagnostic purposes; OR1 comes from the internal bus i.e. from memories, while OR2 gives an opcode copy and additional data to the microcomputer. A four byte, 5-bit stack register and an instruction register, under microcomputer control, store input data available at the interface.

Dedicated logic, under control of the microprocessor interface, extracts the 0 channel content of any selected PCM input bus, using spare cycles of SM.

## **FUNCTIONAL DESCRIPTION OF SPECIFIC MICROPROCESSOR OPERATIONS**

The device, under microprocessor control, performs the following instructions:

- 1 CHANNEL CONNECTION/DISCONNECTION
- 2 CHANNEL DISCONNECTION
- 3 INSERTION OF A BYTE ON A PCM OUTPUT CHANNEL/CHANNEL DISCONNECTION)
- 4 TRANSFER OF A SINGLE OUTPUT CHANNEL SAMPLE
- 5 TRANSFER OF A SINGLE OUTPUT CHANNEL CONTROL WORD
- 6 TRANSFER OF SELECTED 0 CHANNEL PCM INPUT DATA ACCORDING TO AN 8-BIT MASK PREVIOUSLY STORED IN THE "EXPECTED MESSAGES" REGISTER.

The instruction flow is as follows:

Any input protocol is started by the microprocessor interface loading the internal stack register with 2 bytes (4 bytes for instructions 1 and 3) qualified as data bytes by C/D = 0 and a specific opcode qualified by C/D = 1 (match condition is normally needed).

After the code is loaded, the instruction register is immediately checked to see whether it is acceptable; if not, it is rejected. If accepted the instruction is also processed as regards match condition and is appended for execution during the memories' space cycles.

Four cases are possible:

- a) the code is not valid; execution cannot take place, the DR output pin is reset to indicate the error and all registers are saved;
- b) the code is valid for types 2, 4 and 6 but it is unmatched; execution cannot take place, and DR is not affected.
- c) the code is valid for types 1 and 3 and it is unmatched; the instruction is interpreted as a channel disconnection.
- d) the code is valid and it either matches or is of type 5; the instruction is processed as received.

Validation control takes only two cycles out of a total execution time of 5 to 13 cycles; the last operation is the updating of the contents of registers OR1 and OR2.

During a very long internal operation (device initialization after  $\overline{\text{RESET}}$  going high or execution of instruction 6) a new set of data bytes with a valid opcode is accepted while a wrong code is rejected. At the end of the current routine execution takes place in the same way as described before.

At the end of an instruction it is normally recommended to read one or both registers. To enable instruction 6, however, it is necessary to read register OR2. This is because instruction 6, used between other short instructions of type 1 to 5, must have a lower priority and can be enabled only after the short instructions have been completed. Instruction 6 normally has a long process and a special flow which is described below.

First a not-all-zero mask is stored in the “expected messages” register and in another “background” register. This operation starts the second phase of instruction 6 which is called “channel 0 extraction” and is repeated at the beginning of any new time frame. At the beginning of the time frame a new copy of activated channels to be extracted is made from the “background register” and put in the “expected messages” register. In addition the latter register is modified to indicate the exact number of messages that have arrived. The term messages covers any input 0 channel data with starting sequence different from the label 01. So using this label the number of expected messages can be reduced to correspond to the number of effective messages. If and only if the residual number is different from zero will the device start the extraction protocol at the end of the current routine.

The procedure is as follows: the DR output is pulsed low as a two cycle interrupt request and OR2 is loaded with the total number of active channels to be extracted.

The transfer of OR2 contents to the microprocessor continues the extraction which consists of repeated steps of OR1 and OR2 loading, indicating respectively the message and the incoming bus number. Reading the registers in the order OR1, OR2 must be continued until completion or until the time frame runs out.

With a new time frame a new extraction process begins, resuming the copy operation from the background register.

During extraction the active channels are scanned from the highest to the lowest number (from 7 to 0). While extraction is being carried out the time interval requirements between active rising edges of RD are a minimum of 5 to 13  $t_{CK}$  for sequence OR2 - OR1 and a minimum of 3 times  $t_{CK}$  for sequence OR1 - OR2. More details are given in the following tables.

**INSTRUCTION TABLES**

The most significant digits of OR2 A7, A6, A5 are a copy of the PCM selected output bus; the least significant digits or OR2 are the opcode while C8 is the control bit. In all cases parentheses () define actual register contents.

**INSTRUCTION 1: CHANNEL CONNECTION/DISCONNECTION**

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Bi2	Bi1	Bi0	1 <sup>st</sup> Data Byte: selected input bus
X	0	0	0	1	X	X	X	Ci4	Ci3	Ci2	Ci1	Ci0	2 <sup>nd</sup> Data Byte: selected input channel
X	0	0	0	1	X	X	X	X	X	Bo2	Bo1	Bo0	3 <sup>rd</sup> Data Byte: selected output bus
X	0	0	0	1	X	X	X	Co4	Co3	Co2	Co1	Co0	4 <sup>th</sup> Data Byte: selected output channel
Yes/No	1	0	0	1	X	X	X	X	0	0	0	1	Instruction Opcode
Yes	0	0	1	0	C7	C6	C5	C4	C3	C2	C1	C0	OR1 : CM content copy, that is for mismatch condition or match condition (1 1 1 1 1 1 1 1) (Bi2 Bi1 Bi0 Ci4 Ci3 Ci2 Ci1 Ci0)
Yes	1	0	1	0	A7	A6	A5	C8	0	0	0	1	OR2 (Bo2 Bo1 Bo0 1 0 0 0 1) (Bo2 Bo1 Bo0 0 0 0 0 1)

**INSTRUCTION 2: OUTPUT CHANNEL DISCONNECTION**

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Bo2	Bo1	Bo0	1 <sup>st</sup> Data Byte: selected output bus
X	0	0	0	1	X	X	X	Co4	Co3	Co2	Co1	Co0	2 <sup>nd</sup> Data Byte: selected output channel
Yes	1	0	0	1	X	X	X	X	0	0	1	0	Instruction Opcode
Yes	0	0	1	0	1	1	1	1	1	1	1	1	OR1 : CM Content Copy (output channel is inactive)
Yes	1	0	1	0	A7	A6	A5	1	0	0	1	0	OR2 (Bo2 Bo1 Bo0 1 0 0 0 1 0)

**INSTRUCTION 3: LOADING A MICROPROCESSOR BYTE**

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Ci7	Ci6	Ci5	1 <sup>st</sup> Data Byte: most significant digits to be inserted
X	0	0	0	1	X	X	X	Ci4	Ci3	Ci2	Ci1	Ci0	2 <sup>nd</sup> Data Byte: least significant digits to be inserted
X	0	0	0	1	X	X	X	X	X	Bo2	Bo0	Bo1	3 <sup>rd</sup> Data Byte: selected output bus
X	0	0	0	1	X	X	X	Co4	Co3	Co2	Co1	Co0	4 <sup>th</sup> Data Byte: selected output channel
Yes/no	1	0	0	1	X	X	X	X	0	1	0	0	Instruction Opcode
Yes	0	0	1	0	C7	C6	C5	C4	C3	C2	C1	C0 (1 1 1 1 1 1 1 1 1) (Ci7 Ci6 Ci5 Ci4 Ci3 Ci2 Ci1 Ci0)	OR1 : CM content copy, that is for mismatch condition or match condition
Yes	1	0	1	0	A7	A6	A5	1	0	1	0	0	OR2 (Bo2 Bo1 Bo0 1 0 1 0 0)

**INSTRUCTION 4: TRANSFER OF A SINGLE PCM SAMPLE**

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Bo2	Bo1	Bo0	1 <sup>st</sup> Data Byte: selected output bus
X	0	0	0	1	X	X	X	Co4	Co3	Co2	Co1	Co0	2 <sup>nd</sup> Data Byte: selected output channel
Yes	1	0	0	1	X	X	X	X	1	0	1	1	Instruction Opcode
Yes	0	0	1	0	C7	C6	C5	C4	C3	C2	C1	C0 S7 S6 S5 S4 S3 S2 S1 S0	OR1 : CM Content Copy if C8=1; or SM Content Sample if C8=0
Yes	1	0	1	0	A7	A6	A5	C8	1	0	1	1	OR2 (Bo2 Bo1 Bo0 C8 1 0 1 1)

Note: S7..S0 is a parallel copy of the PCM data; S7 is the most significant digit and the first of the sequence.

## INSTRUCTION 5: TRANSFER OF AN OUTPUT CHANNEL CONTROL WORD

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Bo2	Bo1	Bo0	1 <sup>st</sup> Data Byte: selected output bus
X	0	0	0	1	X	X	X	Co4	Co3	Co2	Co1	Co0	2 <sup>nd</sup> Data Byte: selected output channel
X	1	0	0	1	X	X	X	X	1	0	0	0	Instruction Opcode
Yes	0	0	1	0	C7	C6	C5	C4	C3	C2	C1	C0	OR1 : CM selected CM word copy
Yes	1	0	1	0	A7	A6	A5	A8	1	0	0	0	OR2
					(Bo2	Bo1	Bo0	C8	1	0	0	0	

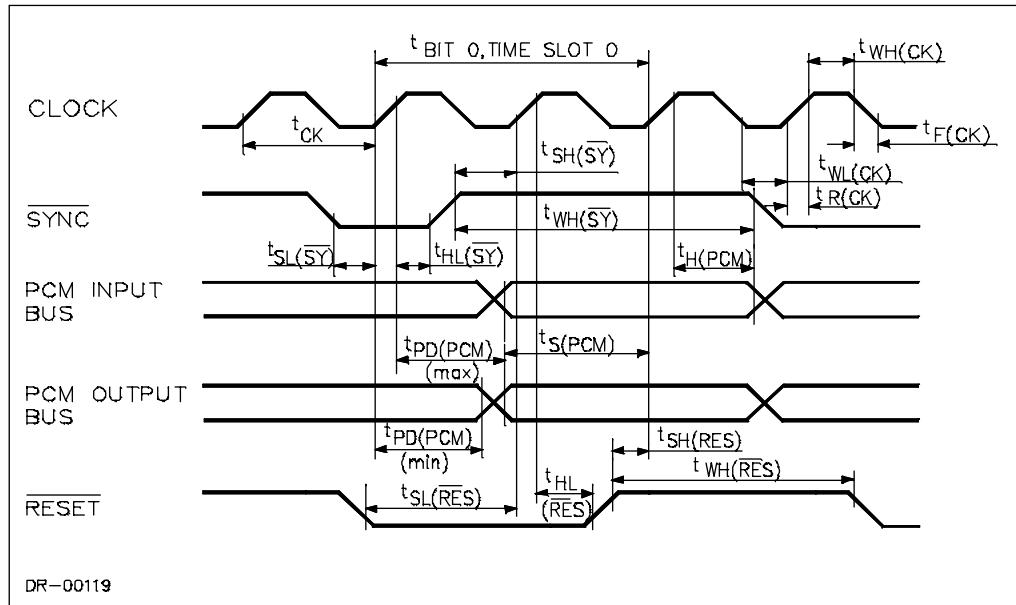
## INSTRUCTION 6: CHANNEL 0 SELECTION MASK STORE/DATA TRANSFER

Control Signals					Data Bus								Notes
Match	C/D	CS	WR	RD	D7	D6	D5	D4	D3	D2	D1	D0	
X	0	0	0	1	X	X	X	X	X	Mi7	Mi6	Mi5	1 <sup>st</sup> Data Byte: most significant digits of selection mask
X	0	0	0	1	X	X	X	Mi4	Mi3	Mi2	Mi1	Mi0	2 <sup>nd</sup> Data Byte: most significant digits of selection mask
Yes	1	0	0	1	X	X	X	X	1	1	1	0	Instruction Opcode
<b>Mask store control</b>													
Yes	0	0	1	0	(previous content)								OR1 : register is not affected
Yes	1	0	1	0	N2	N1	N0	Tn	1	1	1	0	OR2 : see below
<b>First Data Transfer</b> (after DR going low)													
Yes	0	0	1	0	(previous content)								OR1 : register is not affected
Yes	1	0	1	0	N2	N1	N0	Tn	1	1	1	0	OR2 : see below
<b>Repeated Data Transfer</b> (after first OR2 transfer)													
Yes	0	0	1	0	S7	S6	S5	S4	S3	S2	S1	S0	OR1 : expected message stored in SM
Yes	1	0	1	0	P2	P1	P0	Fn	1	1	1	0	OR2

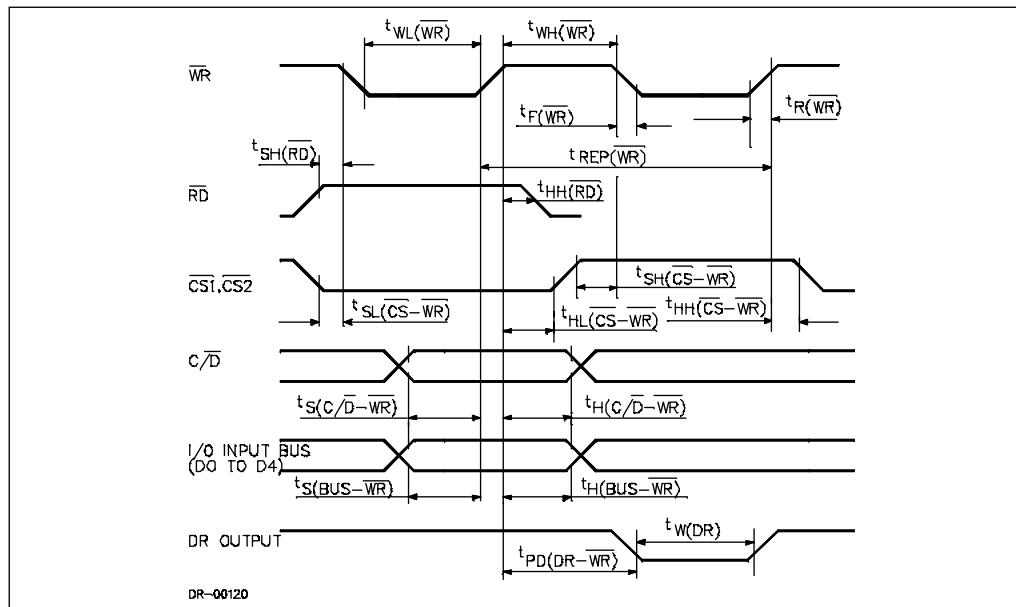
**Notes:**

1. Regarding mask bits Mi0 to Mi7 a logic "0" level means disabling condition, a logic "1" level means enabling condition.
2. A null mask or a RESET pulse clears the mask and the deep background mask registers and disable channel 0 extraction function.
3. Reading of OR2 is optional after mask store or redefinition, because function is activated only by not-null mask writing.
4. After mask store (N2 N1 N0) is the sum of activated channels, after DR is the sum of active channels; Tn=1/0 means activation/suppression of the function after store while after DR only Tn = 1 can appear indicating non-null configuration extraction.
5. Reading of OR2 is imperative after DR in order to step the data transfer; reading of OR1 is also needed to scan in descending order the priority register. Relevant messages only are considered, i.e. only messages with a MSD label different from 0 1.
6. (P2 P1 P0) is the PCM bus on which the message copied in OR1 was found; Fn is a continuation bit telling respectively on level 1/0 for any more/no more extraction to be performed.

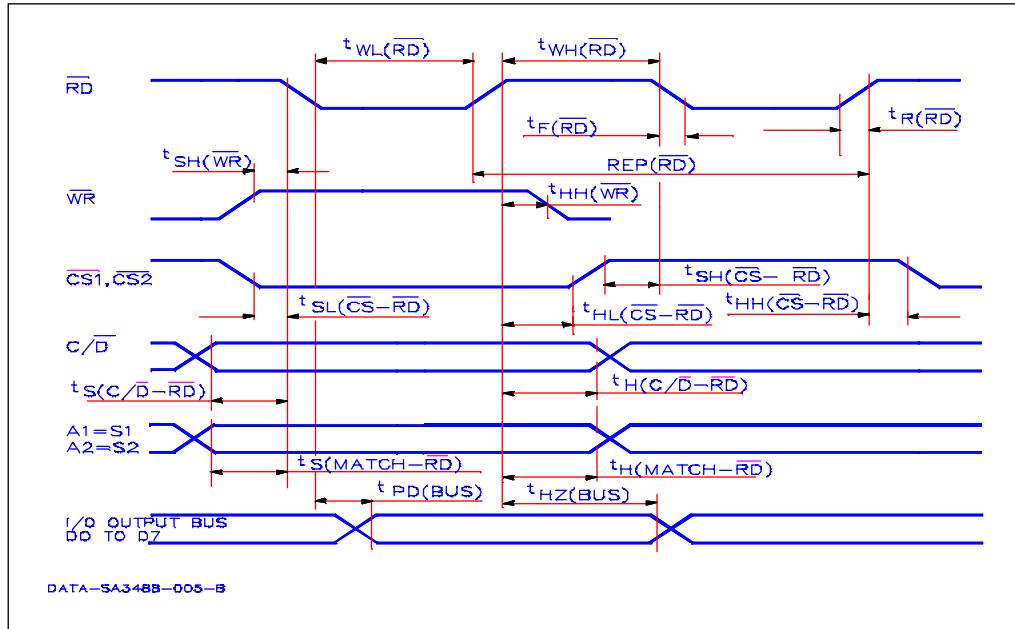
## PCM TIMING, RESET



## WRITE OPERATION TIMING



## READ OPERATION TIMING



**Notes:**

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